# 74HC4060; 74HCT4060 14-stage binary ripple counter with oscillator Rev. 4 — 10 February 2016

Product data sheet

# **General description**

The 74HC4060; 74HCT4060 is a 14-stage ripple-carry counter/divider and oscillator with three oscillator terminals (RS, RTC and CTC), ten buffered parallel outputs (Q3 to Q9 and Q11 to Q13) and an overriding asynchronous master reset (MR). The oscillator configuration allows design of either RC or crystal oscillator circuits. The oscillator may be replaced by an external clock signal at input RS. In this case, keep the oscillator pins (RTC and CTC) floating. The counter advances on the HIGH-to-LOW transition of RS. A HIGH level on MR clears all counter stages and forces all outputs LOW, independent of the other input conditions. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

# **Features and benefits**

- All active components on chip
- RC or crystal oscillator configuration
- Complies with JEDEC standard no. 7 A
- Input levels:
  - For 74HC4060: CMOS level
  - ◆ For 74HCT4060: TTL level
- ESD protection:
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from −40 °C to +85 °C and from −40 °C to +125 °C

# 3. Applications

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

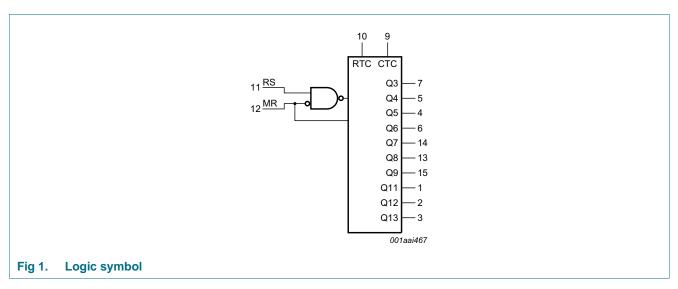


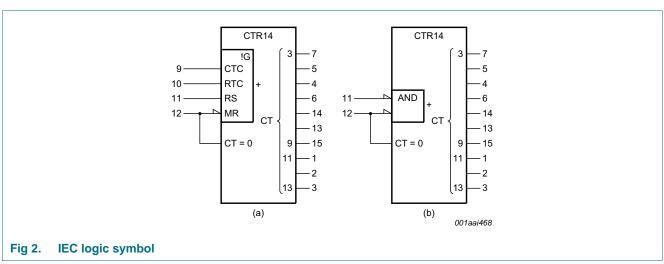
# 4. Ordering information

Table 1. Ordering information

Type number	Package	Package									
	Temperature range	Name	Description	Version							
74HC4060D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT4060D			body width 3.9 mm								
74HC4060DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1							
74HCT4060DB			body width 5.3 mm								
74HC4060PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							
74HC4060BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced	SOT763-1							
74HCT4060BQ			very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm								

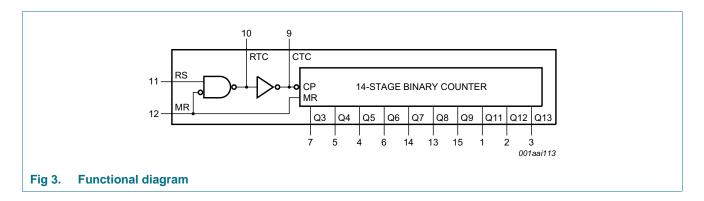
# 5. Functional diagram

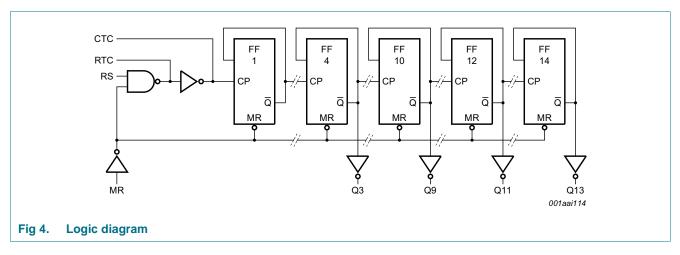




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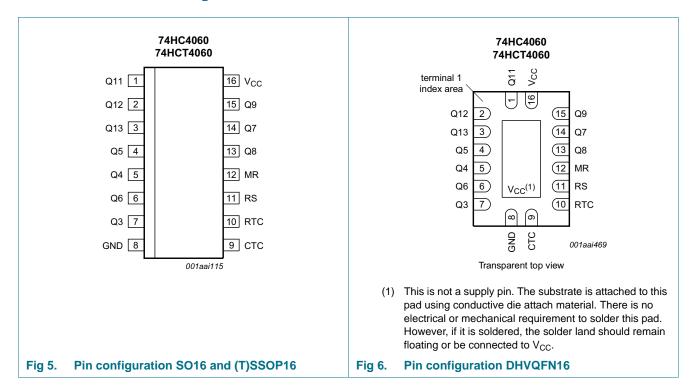
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# 6. Pinning information

# 6.1 Pinning

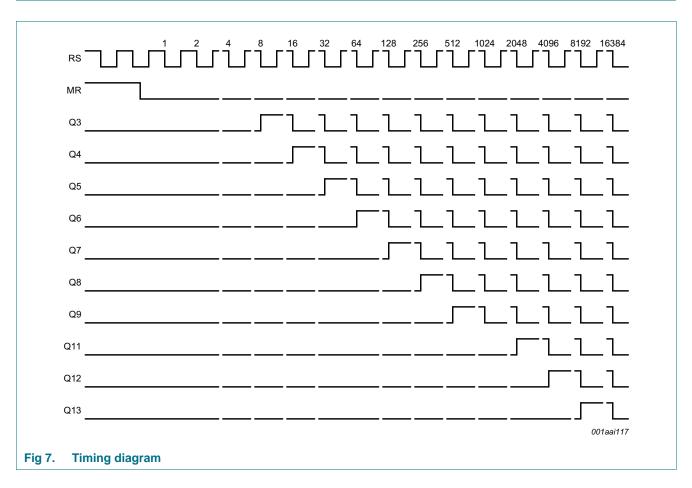


# 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q11 to Q13	1, 2, 3	counter output
Q3 to Q9	7, 5, 4, 6, 14, 13, 15	counter output
GND	8	ground (0 V)
СТС	9	external capacitor connection
RTC	10	external resistor connection
RS	11	clock input /oscillator pin
MR	12	master reset input (active HIGH)
Vcc	16	supply voltage

# 7. Functional description



# 8. Limiting values

#### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		<b>−65</b>	+150	°C

Table 3. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			
		SO16 package [2]	-	500	mW
		(T)SSOP16 package	-	500	mW
		DHVQFN16 package	-	500	mW

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] Ptot derates linearly with 8 mW/K above 70 °C.
- [3] Ptot derates linearly with 5.5 mW/K above 60 °C.
- [4] Ptot derates linearly with 4.5 mW/K above 60 °C.

# 9. Recommended operating conditions

#### Table 4. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	7	'4HC406	0	74	Unit		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
	$V_{CC} = 6.0 \text{ V}$		-	-	83	-	-	-	ns/V

# 10. Static characteristics

#### Table 5. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC406	60									
$V_{IH}$	HIGH-level	MR input								
	input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.3	-	1.5	-	1.5	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.1	-	4.2	-	4.2	-	V
		RS input								
		V <sub>CC</sub> = 2.0 V	1.7	-	-	1.7	-	1.7	-	V
		V <sub>CC</sub> = 4.5 V	3.6	-	-	3.6	-	3.6	-	V
		V <sub>CC</sub> = 6.0 V	4.8	-	-	4.8	-	4.8	-	V

 Table 5.
 Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>IL</sub>	LOW-level	MR input								
	input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
		RS input								
		V <sub>CC</sub> = 2.0 V	-	-	0.3	-	0.3	-	0.3	V
		V <sub>CC</sub> = 4.5 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 6.0 V	-	-	1.2	-	1.2	-	1.2	V
V <sub>OH</sub>		RTC output; RS = MR = GND								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
	voitage	$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -2.6 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -3.3 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V
		RTC output; RS = MR = V <sub>CC</sub>								
		$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 \text{ V}$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -0.65 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -0.85 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V
		CTC output; RS = V <sub>IH</sub> ; MR = V <sub>IL</sub>								
		$I_{O} = -3.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -4.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A$ ; $V_{CC} = 6.0 \text{ V}$	5.9	6.0	-	5.9	-	5.9	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC and CTC outputs								
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_O = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

 Table 5.
 Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OL</sub>	LOW-level output	RTC output; RS = V <sub>CC</sub> ; MR = GND								
	voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 2.6 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		$I_O = 3.3 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		CTC output; RS = V <sub>IL</sub> ; MR = V <sub>IH</sub>								
		$I_O = 3.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		$I_O = 4.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$V_I = V_{IH}$ or $V_{IL}$ ; except RTC and CTC outputs								
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	060								-	
V <sub>IH</sub>	HIGH-level input voltage	MR input; [1] V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
		RS input; V <sub>CC</sub> = 4.5 V	3.6	-	-	3.6	-	3.6	-	V
V <sub>IL</sub>	LOW-level input voltage	MR input; [1] V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	8.0	-	0.8	-	0.8	V
		RS input; V <sub>CC</sub> = 4.5 V	-	-	0.9	-	0.9	-	0.9	V

 Table 5.
 Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OH</sub>	HIGH-level	RTC output; RS = MR = V <sub>CC</sub>								
	output	$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
	voltage	$I_{O} = -0.65 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		RTC output; RS = MR = GND								
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -2.6 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		CTC output; RS = V <sub>IH</sub> ; MR = V <sub>IL</sub>								
		$I_{O} = -3.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
		$I_O = -20 \mu A$ ; $V_{CC} = 4.5 \text{ V}$	4.4	4.5	-	4.4	-	4.4	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC and CTC outputs								
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level output voltage	RTC output; RS = V <sub>CC</sub> ; MR = GND								
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 2.6 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		CTC output; RS = V <sub>IL</sub> ; MR = V <sub>IH</sub>								
		$I_O = 3.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$V_I = V_{IH}$ or $V_{IL}$ ; except RTC and CTC outputs								
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	8.0	-	80	-	160	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$	-	40	144	-	180	-	196	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

<sup>[1]</sup> For HCT4060, only input MR (pin 12) has TTL input switching levels.

# 11. Dynamic characteristics

Table 6. Dynamic characteristics

GND = 0 V;  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see Figure 11.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	60			1						
t <sub>pd</sub>	propagation	RS to Q3; see Figure 8	]							
	delay	V <sub>CC</sub> = 2.0 V	-	99	300	-	375	-	450	ns
		V <sub>CC</sub> = 4.5 V	-	36	60	-	75	-	90	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	31	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	29	51	-	64	-	77	ns
		Qn to Qn+1; see Figure 9	1							
		V <sub>CC</sub> = 2.0 V	-	22	80	-	100	-	120	ns
		V <sub>CC</sub> = 4.5 V	-	8	16	-	20	-	24	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	6	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	6	14	-	17	-	20	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; see Figure 10								
	propagation	V <sub>CC</sub> = 2.0 V	-	55	175	-	220	-	265	ns
	delay	V <sub>CC</sub> = 4.5 V	-	20	35	-	44	-	53	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	16	30	-	37	-	45	ns
t <sub>t</sub>	transition time	Qn; see Figure 8	1							
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	RS (HIGH or LOW); see Figure 8								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		MR (HIGH); see Figure 10								
		V <sub>CC</sub> = 2.0 V	80	25	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	9	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	7	-	17	-	20	-	ns
t <sub>rec</sub>	recovery time	MR to RS; see Figure 10								
		V <sub>CC</sub> = 2.0 V	100	28	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	8	-	21	-	26	-	ns

 Table 6.
 Dynamic characteristics ...continued

GND = 0 V;  $C_L$  = 50 pF unless otherwise specified; for test circuit see <u>Figure 11</u>.

Symbol	Parameter	Conditions		25 °C		–40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
f <sub>max</sub>	maximum	RS; see Figure 8								
	frequency	V <sub>CC</sub> = 2.0 V	6	26	-	4.8	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	80	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	87	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	95	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ $V_{CC} = 5 \text{ V}; f_i = 1 \text{ MHz}$	<u>1</u> ] -	40	-	-	-	-	-	pF
74HCT40	060						1	1		
t <sub>pd</sub>	propagation	RS to Q3; see Figure 8	1]							T
	delay	V <sub>CC</sub> = 4.5 V	-	33	66	-	83	-	99	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	31	-	-	-	-	-	ns
		Qn to Qn+1; see Figure 9	2]							
		V <sub>CC</sub> = 4.5 V	-	8	16	-	20	-	24	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	6	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; see Figure 10								
	propagation	V <sub>CC</sub> = 4.5 V	-	21	44	-	55	-	66	ns
	delay	$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	18	-	-	-	-	-	ns
t <sub>t</sub>	transition time	Qn; see Figure 8	3]							
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	RS (HIGH or LOW); see Figure 8								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		MR (HIGH); see Figure 10								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
t <sub>rec</sub>	recovery time	MR to RS; see Figure 10								
		V <sub>CC</sub> = 4.5 V	26	13	-	33	-	39	-	ns
f <sub>max</sub>	maximum	RS; see Figure 8								
	frequency	V <sub>CC</sub> = 4.5 V	30	80	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	88	-	-	-	-	-	MHz

Table 6. Dynamic characteristics ...continued

GND = 0 V;  $C_L$  = 50 pF unless otherwise specified; for test circuit see <u>Figure 11</u>.

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		–40 °C to	Unit		
			Min	Тур	Max	Min	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V};$ [4] $V_{CC} = 5 \text{ V}; f_i = 1 \text{ MHz}$	-	40	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .
- [2] Qn+1 is the next Qn output.
- [3]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

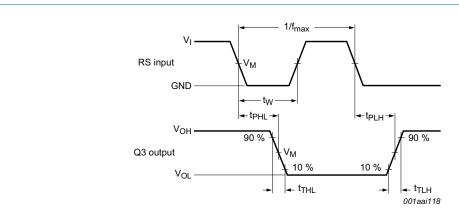
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

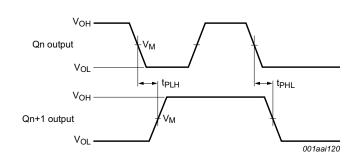
# 12. Waveforms



Measurement points are given in Table 7.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

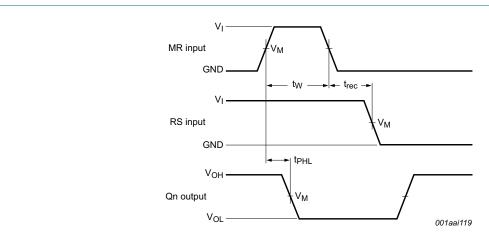
Fig 8. Waveforms showing the clock (RS) to output (Q3) propagation delays, the clock pulse width, the output transition times and the maximum clock frequency



Measurement points are given in Table 7.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig 9. Waveforms showing the output Qn to output Qn+1 propagation delays



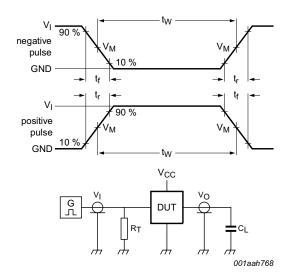
Measurement points are given in Table 7.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig 10. Waveforms showing the master reset (MR) pulse width, the master reset to output (Qn) propagation delays and the master reset to clock (RS) recovery time

Table 7. Measurement points

Туре	Input	Output		
	V <sub>M</sub>	V <sub>M</sub>		
74HC4060	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$		
74HCT4060	1.3 V	1.3 V		



Test data is given in Table 8.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

Fig 11. Test circuit for measuring switching times

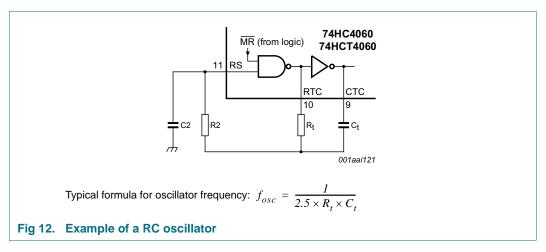
Table 8. Test data

Туре	Input	Load	
	VI	t <sub>r</sub> , t <sub>f</sub>	CL
74HC4060	V <sub>CC</sub>	6 ns	15 pF, 50 pF
74HCT4060	3 V	6 ns	15 pF, 50 pF

# 13. RC oscillator

# 13.1 Timing component limitations

The oscillator frequency is mainly determined by  $R_tC_t$ , provided  $R2 \approx 2R_t$  and  $R2C2 << R_tC_t$ . The function of R2 is to minimize the influence of the forward voltage across the input protection diodes on the frequency. The stray capacitance C2 should be kept as small as possible. In consideration of accuracy,  $C_t$  must be larger than the inherent stray capacitance.  $R_t$  must be larger than the ON resistance in series with it, which typically is  $280~\Omega$  at  $V_{CC} = 2.0~V$ ,  $130~\Omega$  at  $V_{CC} = 4.5~V$  and  $100~\Omega$  at  $V_{CC} = 6.0~V$ .



The recommended values for these components to maintain agreement with the typical oscillation formula are:

 $C_t > 50$  pF, up to any practical value and 10 k $\Omega$  <  $R_t < 1$  M $\Omega$ .

In order to avoid start-up problems,  $R_t \ge 1 \text{ k}\Omega$ .

## 13.2 Typical crystal oscillator circuit

In <u>Figure 13</u>, R2 is the power limiting resistor. For starting and maintaining oscillation a minimum transconductance is necessary, so R2 should not be too large. A practical value for R2 is  $2.2 \text{ k}\Omega$ .

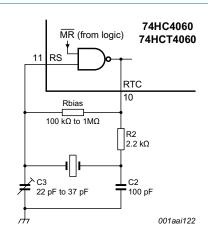
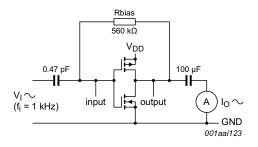


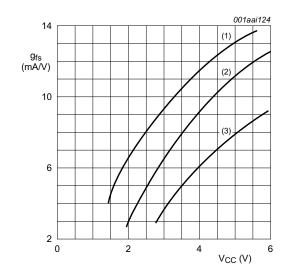
Fig 13. External component connection for a crystal oscillator



 $g_{fs} = \Delta I_O / \Delta V_I$  at  $V_O$  is constant; MR = LOW.

See also Figure 15.

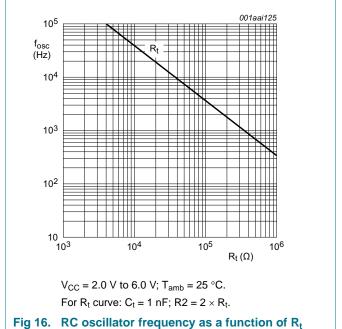
Fig 14. Test set-up for measuring forward transconductance



 $T_{amb} = 25 \, ^{\circ}C.$ 

- (1) Maximum.
- (2) Typical.
- (3) Minimum.

Fig 15. Typical forward transconductance as function of the supply voltage



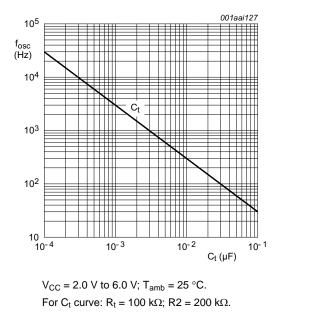
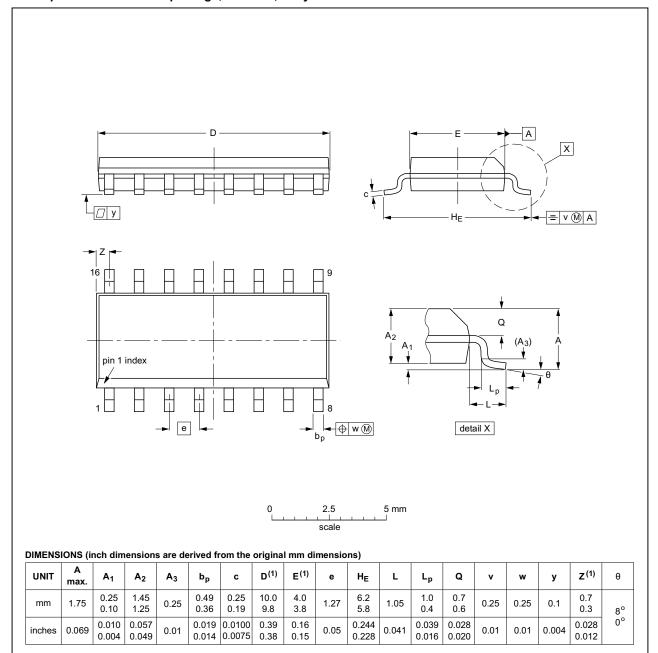


Fig 17. RC oscillator frequency as a function of Ct

# 14. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19	

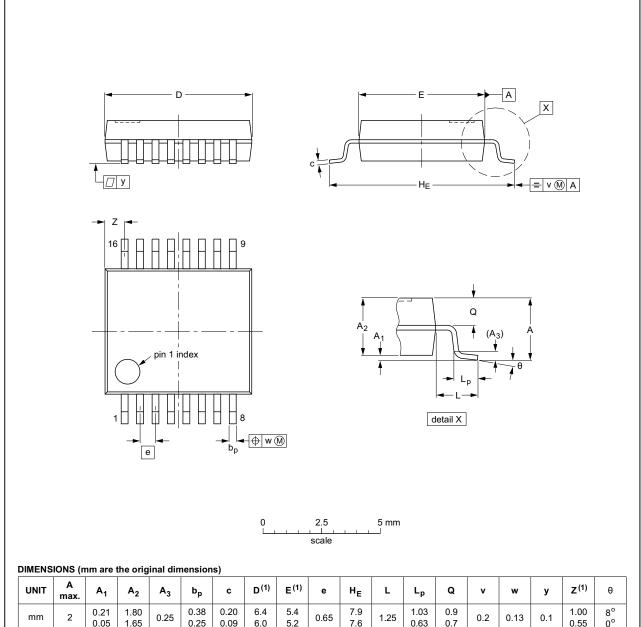
Fig 18. Package outline SOT109-1 (SO16)

74HC\_HCT4060

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# SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	b <sub>p</sub>	U	D <sup>(1)</sup>	E <sup>(1)</sup>	e	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT338-1		MO-150		$ \  \   \bigoplus  \big($	<del>99-12-27</del> 03-02-19

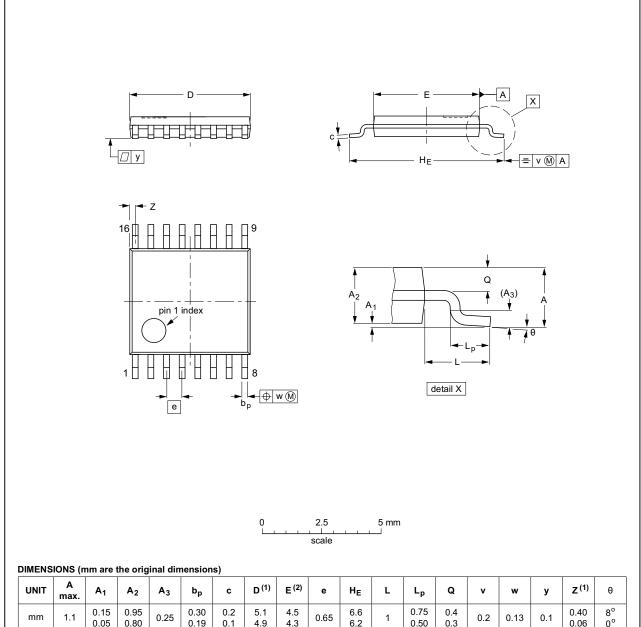
Fig 19. Package outline SOT338-1 (SSOP16)

74HC\_HCT4060

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	TA PROJECTION		ISSUE DATE	
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	

Fig 20. Package outline SOT403-1 (TSSOP16)

74HC\_HCT4060

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

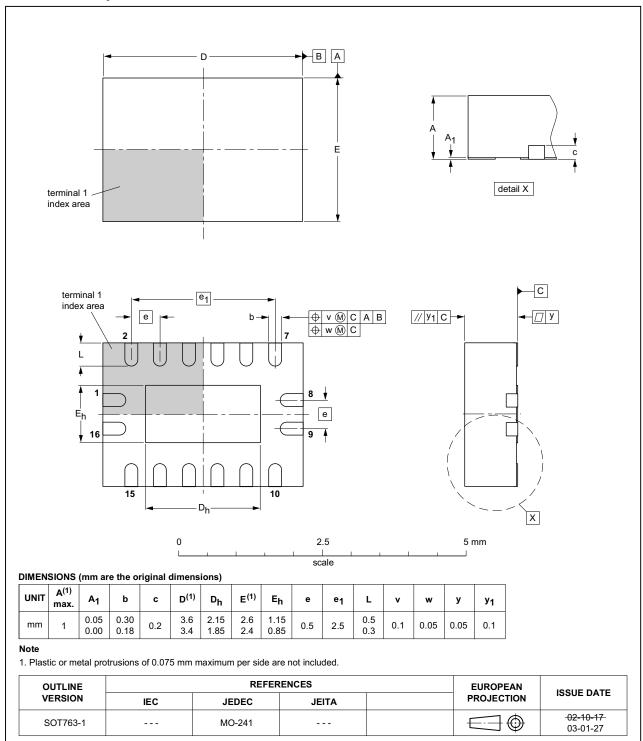


Fig 21. Package outline SOT763-1 (DHVQFN16)

74HC\_HCT4060

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# 15. Abbreviations

#### Table 9. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 16. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74HC_HCT4060 v.4	20160210	Product data sheet	-	74HC_HCT4060 v.3				
Modifications:	Type numbe	rs 74HC4060N and 74HCT	4060N (SOT38-4	removed.				
	• <u>Table 5</u> : HIG	H and LOW input levels ac	Ided for 74HCT40	60. (errata)				
74HC_HCT4060 v.3	20080714	Product data sheet	-	74HC_HCT4060_CNV v.2				
Modifications:		f this data sheet has been NXP Semiconductors.	redesigned to con	nply with the new identity				
	<ul> <li>Legal texts h</li> </ul>	ave been adapted to the n	ew company name	e where appropriate.				
	• Section 4: D	HVQFN16 package added						
	Section 8: de	<ul> <li><u>Section 8</u>: derating values added for DHVQFN16 package.</li> </ul>						
	• <u>Section 14</u> : 0	outline drawing added for D	HVQFN16 packa	ge.				
74HC_HCT4060_CNV v.2	19970901	Product specification	-	-				

# 17. Legal information

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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74HC HCT4060

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# 74HC4060; 74HCT4060

## 14-stage binary ripple counter with oscillator

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